





Operating Temperature Range – -40°C to +85°C PD -24.704M

Nominal Frequency

- Pin 1 Connection

Power Down (Disable Output: Logic Low)

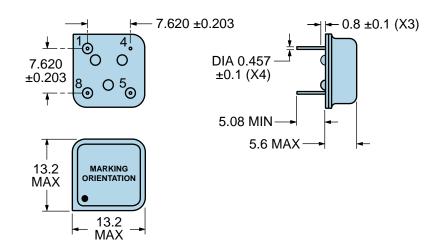
- Duty Cycle 50 ±10(%)

Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration) Aging at 25°C ±5ppm/year Maximum -40°C to +85°C Supply Voltage 3.3Vdc ±0.3Vdc Input Current 28mA Maximum (Unloaded) Output Voltage Logic High (Voh) Vdd-0.4Vdc Minimum (IOH = -8mA) Output Voltage Logic Low (Vol) 0.4Vdc Maximum (IOL = +8mA) Rise/Fall Time 4nSec Maximum (Measured at 20% to 80% of waveform) Duty Cycle 50 ±10(%) (Measured at 50% of waveform) Output Logic Type CMOS Pin 1 Connection Power Down (Disable Output: Logic Low) Pin 1 Input Voltage (Vih and Vil) 70% of Vdd Minimum to enable output, 20% of Vdd Maximum to disable output, No Connect to enable output. Standby Current 20µA Maximum (Pin 1 = Ground) Disable Current 16mA Maximum (Pin 1 = Ground) Peak to Peak Jitter (tPK) 13pSec Maximum, 10pSec Typical	ELECTRICAL SPECIFICATIONS		
Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration) 45ppm/year Maximum Operating Temperature Range	Nominal Frequency	24.704MHz	
Operating Temperature Range -40°C to +85°C Supply Voltage 3.3Vdc ±0.3Vdc Input Current 28mA Maximum (Unloaded) Output Voltage Logic High (Voh) Vdd-0.4Vdc Minimum (IOH = -8mA) Output Voltage Logic Low (Vol) 0.4Vdc Maximum (IOL = +8mA) Rise/Fall Time 4nSec Maximum (Measured at 20% to 80% of waveform) Duty Cycle 50 ±10(%) (Measured at 50% of waveform) Load Drive Capability 30pF Maximum Output Logic Type CMOS Pin 1 Connection Power Down (Disable Output: Logic Low) Pin 1 Input Voltage (Vih and Vil) 70% of Vdd Minimum to enable output, 20% of Vdd Maximum to disable output, No Connect to enable output. Standby Current 20µA Maximum (Pin 1 = Ground) Disable Current 16mA Maximum (Pin 1 = Ground) Peak to Peak Jitter (tPK) 13pSec Maximum, 10pSec Typical	Frequency Tolerance/Stability		
Supply Voltage 3.3Vdc ±0.3Vdc Input Current 28mA Maximum (Unloaded) Output Voltage Logic High (Voh) Vdd-0.4Vdc Minimum (IOH = -8mA) Output Voltage Logic Low (Vol) 0.4Vdc Maximum (IOL = +8mA) Rise/Fall Time 4nSec Maximum (Measured at 20% to 80% of waveform) Duty Cycle 50 ±10(%) (Measured at 50% of waveform) Load Drive Capability 30pF Maximum Output Logic Type CMOS Pin 1 Connection Power Down (Disable Output: Logic Low) Pin 1 Input Voltage (Vih and Vil) 70% of Vdd Minimum to enable output, 20% of Vdd Maximum to disable output, No Connect to enable output. Standby Current 20µA Maximum (Pin 1 = Ground) Disable Current 16mA Maximum (Pin 1 = Ground) Peak to Peak Jitter (tPK) 100pSec Maximum, 60pSec Typical RMS Period Jitter (tRMS) 13pSec Maximum, 10pSec Typical	Aging at 25°C	±5ppm/year Maximum	
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RMS Period Jitter (tRMS) 13pSec Maximum, 10pSec Typical	Disable Current	16mA Maximum (Pin 1 = Ground)	
	Peak to Peak Jitter (tPK)	100pSec Maximum, 60pSec Typical	
Chart Ha Time	RMS Period Jitter (tRMS)	13pSec Maximum, 10pSec Typical	
Start Up Time TumSec Waximum	Start Up Time	10mSec Maximum	
Storage Temperature Range -55°C to +125°C	Storage Temperature Range	-55°C to +125°C	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	
Gross Leak Test	MIL-STD-883, Method 1014, Condition C	
Lead Integrity	MIL-STD-883, Method 2004	
Mechanical Shock	MIL-STD-202, Method 213, Condition C	
Resistance to Soldering Heat	MIL-STD-202, Method 210	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010	
Vibration	MIL-STD-883, Method 2007, Condition A	



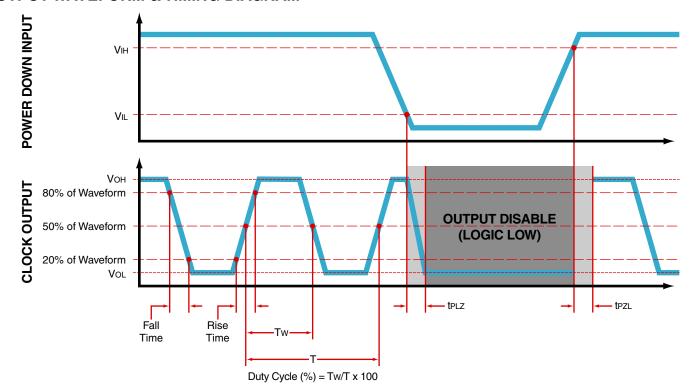
MECHANICAL DIMENSIONS (all dimensions in millimeters)



PIN	CONNECTION
1	Power Down (Logic Low)
4	Case/Ground
5	Output
8	Supply Voltage

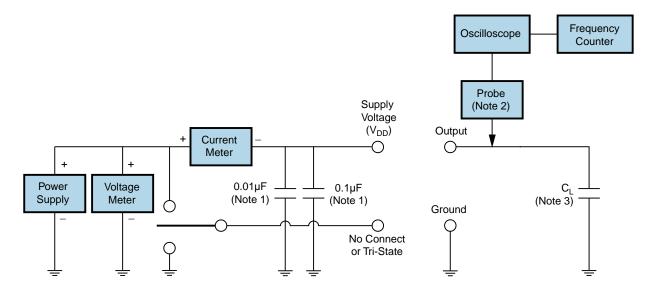
LINE	MARKING
1	ECLIPTEK
2	EP13PD EP13=Product Series
3	24.704M
4	XXYZZ XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year

OUTPUT WAVEFORM & TIMING DIAGRAM





Test Circuit for CMOS Output



Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Solder Bath (Wave Solder)

<u> </u>	, , , , , , , , , , , , , , , , , , ,
T _s MAX to T _L (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _s MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T _L)	217°C
- Time (t _L)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 185°C

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _S MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	185°C Maximum
Target Peak Temperature (T _P Target)	185°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Solder Bath (Wave Solder)

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _S TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	30 - 60 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	245°C Maximum
Target Peak Temperature (T _P Target)	245°C Maximum 1 Time / 235°C Maximum 2 Times
Time within 5°C of actual peak (tp)	5 seconds Maximum 1 Time / 15 seconds Maximum 2 Times
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.